

FEATURES	APPLICATIONS
<ul style="list-style-type: none"> ±20ppm (Frequency Stability) Available Ceramic Package CMOS RoHS Compliant Tape and Reel 	<ul style="list-style-type: none"> Micro Processors SONET/SDH/DWDM Storage Area/Networking Digital Video Base Stations

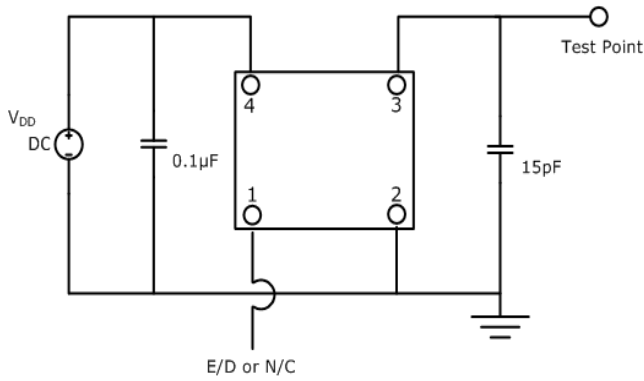


PART NUMBERING GUIDE	
<p>SUNTSU OSC → SXO 53 C 3 A 48 1 X - 50.000M ← FREQUENCY (MHz)</p> <p>5.0mm x 3.2mm</p> <p>CMOS</p> <p>SUPPLY VOLTAGE 1: 1.8V±5% 2: 2.5V±5% 3: 3.3V±5%</p> <p>FREQUENCY STABILITY A: ±50ppm B: ±30ppm C: ±25ppm *D: ±20ppm</p> <p>Cage Code: 4GUT4 To customize your parameters contact a Suntsu representative. * For frequency stability option D contact a Suntsu representative. ** For operating temperatures up to -55~125°C contact a Suntsu representative.</p>	<p>LOAD BLANK: 15pF X: 30pF Y: 50pF</p> <p>TRI-STATE (ENABLE/DISABLE) BLANK: NO CONNECTION 1: Pin 1</p> <p>OPERATING TEMPERATURE RANGE 07: 0°C to +70°C 16: -10°C to +60°C 17: -10°C to +70°C 27: -20°C to +70°C 38: -30°C to +85°C 48: -40°C to +85°C</p>

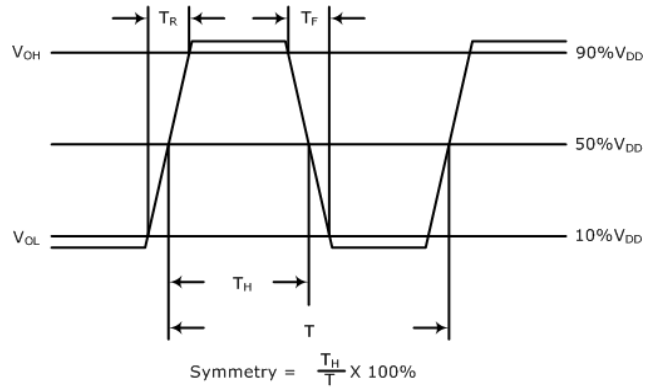
ELECTRICAL PARAMETERS		UNITS	MIN.	TYP.	MAX.	REMARKS
Frequency Range		kHz	32.768			
		MHz	1		200	
Frequency Stability (Includes Initial Tolerance at 25°C, Frequency Stability over Operating Temperature, Output Load Change, Supply Voltage Change, and First Year Aging at 25°C.)		ppm	-20		+20	See part numbering guide for options.
Operating Temperature		°C	-40		+85	See part numbering guide for options.
Storage Temperature			-55		+125	
Supply Voltage (V _{DD})	1.8V Option	V	1.710	1.8	1.890	
	2.5V Option		2.375	2.5	2.625	
	3.3V Option		3.135	3.3	3.465	
Current (I _{DD})	Frequency Range		1.8V	2.5V	3.3V	
	32.768kHz	mA	5	5	5	Maximum value.
	1.0000MHz ~ 34.999MHz		8	10	16	Maximum value.
	35.000MHz ~ 59.999MHz		10	20	25	Maximum value.
	60.000MHz ~ 99.999MHz		25	30	40	Maximum value.
100.00MHz ~ 160.00MHz	35		40	50	Maximum value.	
Output Load (CMOS)		pF			15	See part numbering guide for options.
Output Logic Levels	Output Logic High (V _{OH})	V	0.9* V _{DD}			
	Output Logic Low (V _{OL})			0.1* V _{DD}		
Rise (T _R) and Fall (T _F) Time	32.768kHz	ns			200	
	1.0000MHz ~ 34.999MHz				10	
	35.000MHz ~ 99.999MHz				6	
	100.00MHz ~ 160.00MHz				3	
Symmetry (Duty Cycle)		%	45	50	55	
Tri-State Input Voltage	Enable	V	0.7* V _{DD}			No Connection.
	Disable			0.3* V _{DD}		
Start-Up Time		ms			10	
Phase Jitter (12kHz ~ 20MHz)		ps			1	

OUTLINE DRAWING											
	<p>RECOMMENDED LAND PATTERN</p>										
	<table border="1"> <thead> <tr> <th>PIN</th> <th>FUNCTION</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>TRI-STATE or NC</td> </tr> <tr> <td>2</td> <td>GND</td> </tr> <tr> <td>3</td> <td>OUTPUT</td> </tr> <tr> <td>4</td> <td>V_{DD}</td> </tr> </tbody> </table>	PIN	FUNCTION	1	TRI-STATE or NC	2	GND	3	OUTPUT	4	V _{DD}
PIN	FUNCTION										
1	TRI-STATE or NC										
2	GND										
3	OUTPUT										
4	V _{DD}										
NOTE: Dimensions in millimeters (mm).											

TEST CIRCUIT (CMOS)

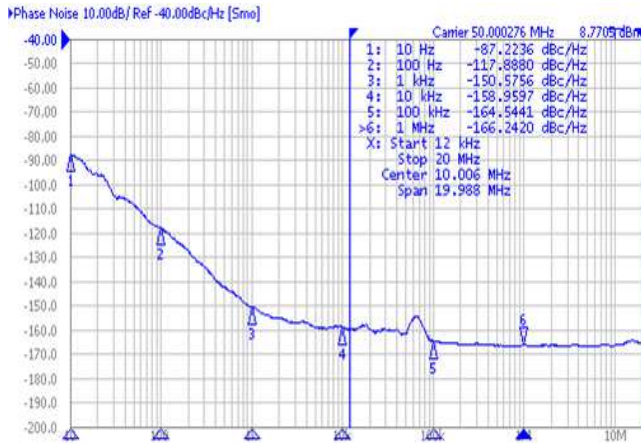


WAVEFORM (CMOS)

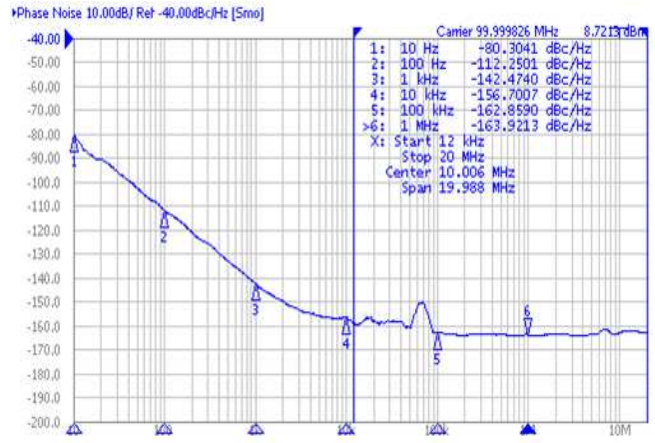


TYPICAL PHASE NOISE PERFORMANCE (MEASURED BY AGILENT E5052A)

Frequency 50.000MHz

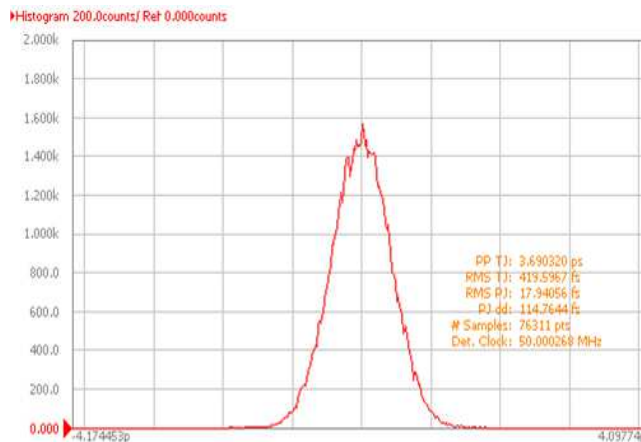


Frequency 100.000MHz

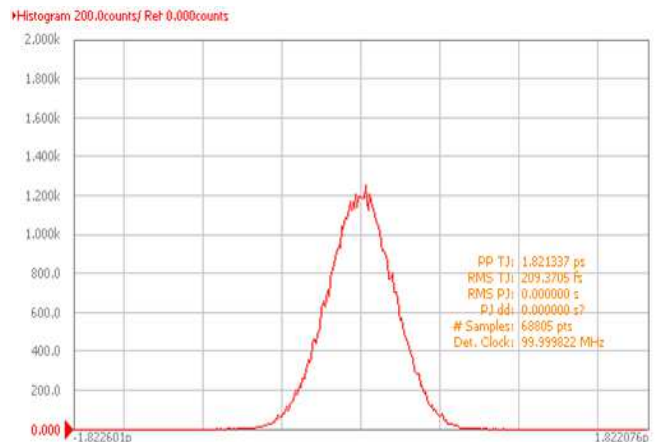


TYPICAL JITTER PERFORMANCE (MEASURED BY AGILENT E5052A)

Frequency 50.000MHz



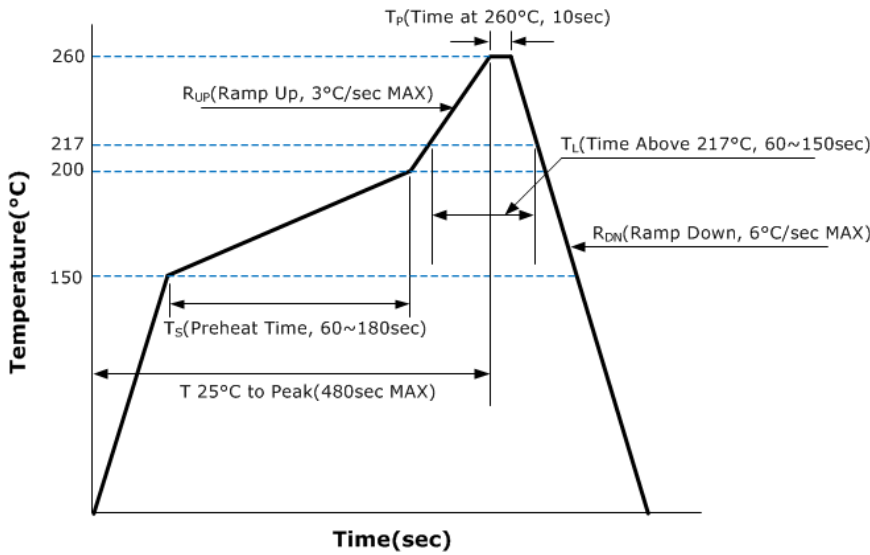
Frequency 100.000MHz



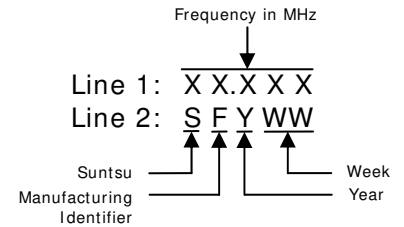
ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

Temperature Cycling	MIL-STD-883, Method 1010, Condition B
Fine Leak Test	MIL-STD-883, Method 1014, Condition A
Gross Leak Test	MIL-STD-883, Method 1014, Condition C
Mechanical Shock	MIL-STD-883, Method 2002, Condition B
Vibration	MIL-STD-883, Method 2007, Condition A
Moisture Resistance	MIL-STD-883, Method 1004
Moisture Sensitivity	J-STD-020, MSL 1
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003

REFLOW PROFILE

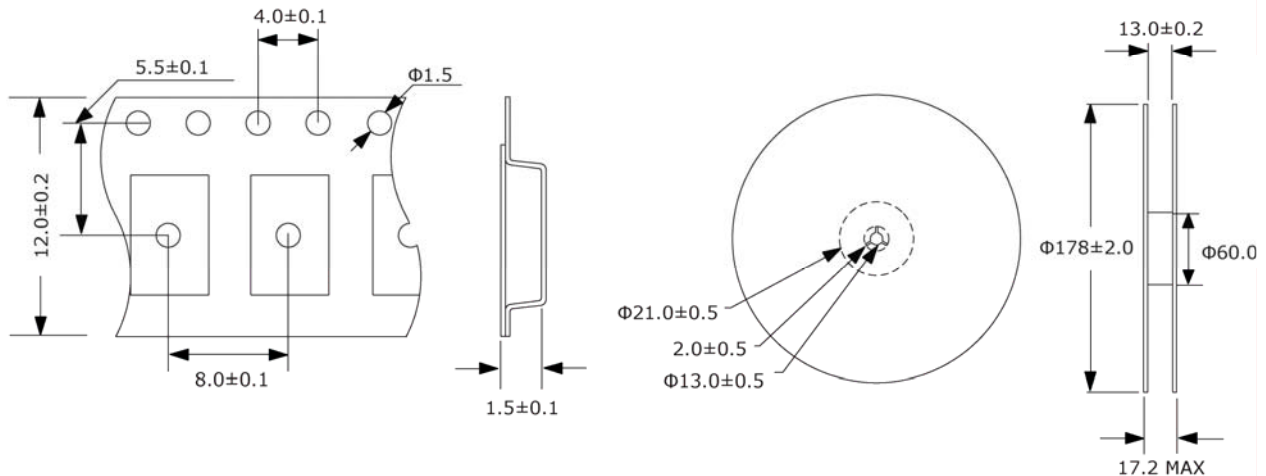


MARKING



TAPE AND REEL DIMENSIONS

1,000pcs/reel



NOTE: Dimensions in millimeters (mm); drawing is not to scale.